

1. Sketch the cross section of a standard bipolar junction transistor (BJT). To obtain a BJT of high current gain ( $\beta$ ), what should be done in the device structure? (10%)
2. Does any internal current exist for the open-circuit PN junction? Why? (7%)
3. Sketch the basic BiCMOS logic inverter and describe its characteristic (10%)
4. Sketch the cross section of a double-diffused (DMOS) power MOSFET and describe its operation. (10%)
5. Derive the barrier voltage (built-in voltage)  $V_0$  of a PN junction with doping concentration in N-type  $N_D$ , doping concentration in P-type  $N_A$ , thermal voltage  $V_T$ , and intrinsic concentration  $n_i$ . (hint: starting with  $J = q\mu_p E - qD_p \frac{dP}{dx}$ ) (13%)
6. For the logic diagram of Fig. 6, draw the waveforms for the clock pulse,  $Q_0$ ,  $Q_1$ ,  $Q_2$ , and  $Q_3$  (starting with 0000). This system is a N:1 counter. What is N? (13%)

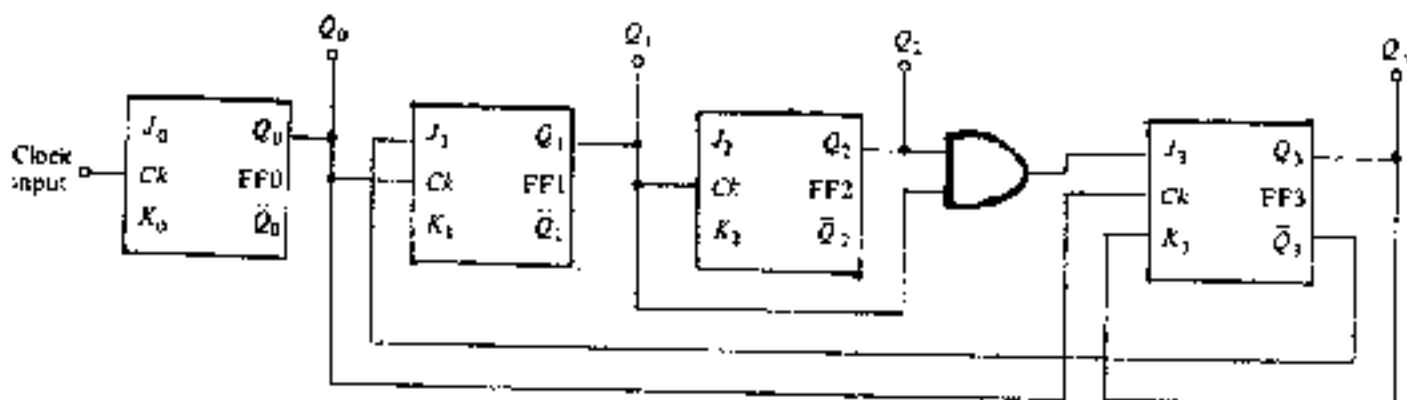


Fig. 6

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7. For the circuit of Fig. 7, sketch the transfer characteristic  $V_o-V_i$ . The diodes have a constant 0.7-V drop when conducting. (7%)

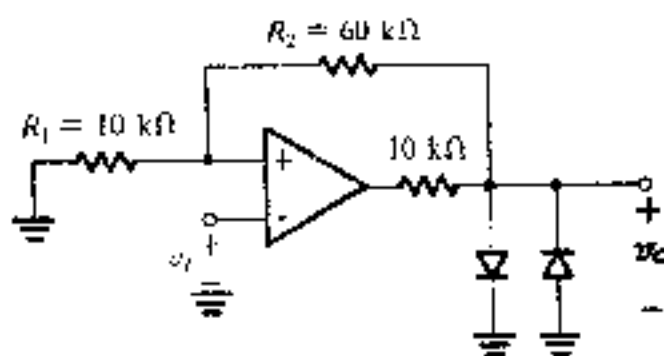


Fig. 7

8. Analyze the high-frequency response of the CMOS amplifier shown in Fig. 8. The dc bias current is  $10\text{ }\mu\text{A}$ . For  $Q_1$ ,  $\mu_n C_{ox} = 20\text{ }\mu\text{A/V}^2$ ,  $V_A = 50\text{ V}$ ,  $W/L = 64$ , and  $C_{gs} = C_{gd} = 1\text{ pF}$ . For  $Q_2$ ,  $C_{gd} = 1\text{ pF}$  and  $V_A = 50\text{ V}$ . There is a 1-pF stray capacitance between the common drain connection and ground. Assume that the resistance of the input signal generator is negligibly small and the signal voltage at the gate of  $Q_2$  is zero. Find the frequency of the pole and zero. (15%)

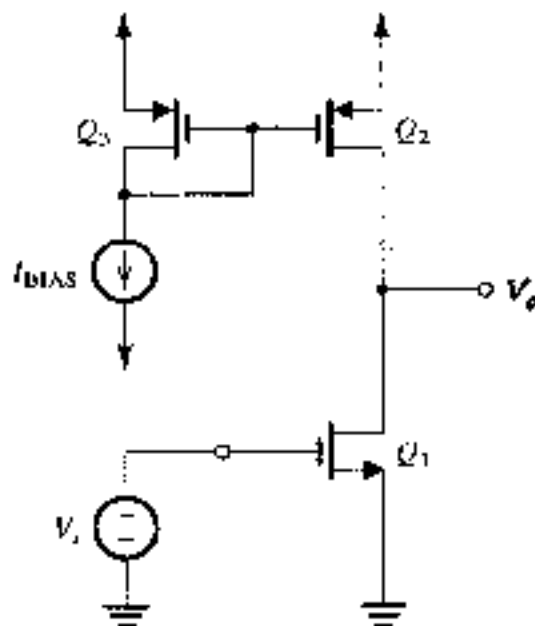


Fig 8

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9. For the circuit of Fig. 9,  $|V_t| = 1\text{ V}$ ,  $K = 0.5\text{ mA/V}^2$ ,  $h_{fe} = 100$ , and the Early voltage magnitude for all devices (including those that implement the current source) is  $100\text{ V}$ . The signal source  $V_s$  has a zero dc component. Find the dc voltage at the output and at the base of  $Q_3$ . Find the values of  $A_v$ ,  $\beta$ ,  $A_{v_f}$ ,  $R'_{if}$  and  $R'_{of}$ . (15%)

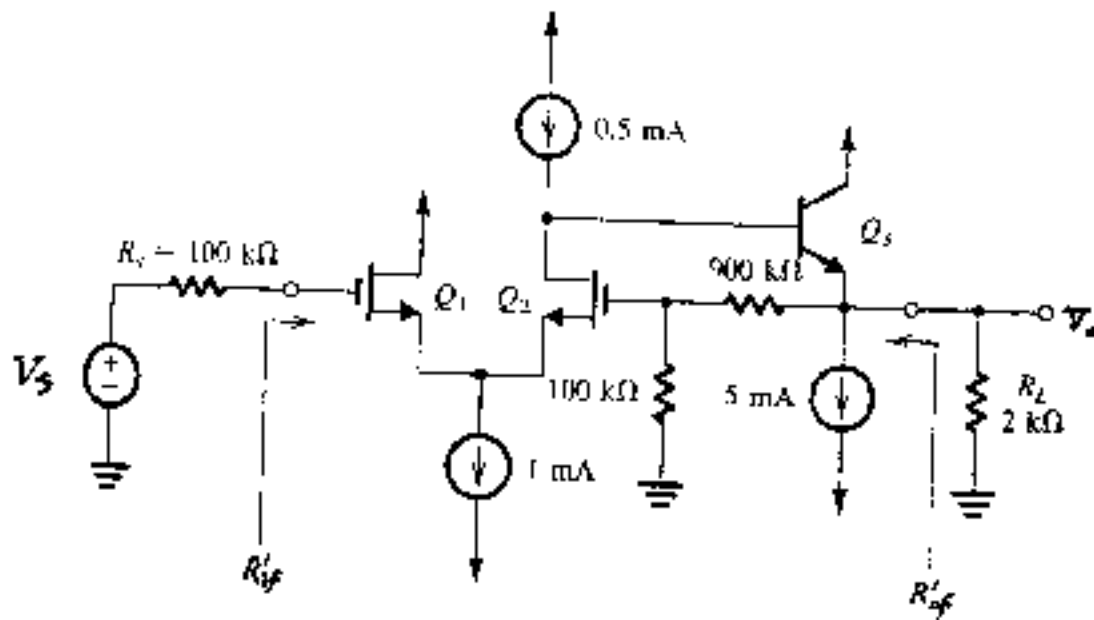


Fig. 9